

RJE0603JPE

Silicon P Channel MOS FET Series Power Switching

R07DS0193EJ0200 (Previous: REJ03G1907-0100) Rev.2.00

Nov 04, 2010

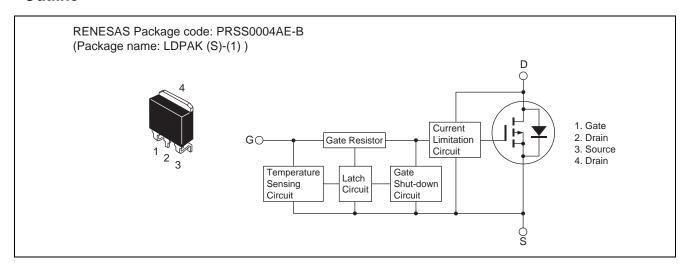
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- High endurance capability against to the short circuit.
- Built-in the over temperature shut-down circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

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Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-60	V
Gate to source voltage	V_{GSS}	-16	V
Gate to source voltage	V_{GSS}	2.5	V
Drain current	I _D	-50 Note3	Α
Body-drain diode reverse drain current	I _{DR}	-50	Α
Avalanche current	I _{AP} Note 2	-15	Α
Avalanche energy	E _{AR} Note 2	964	mJ
Channel dissipation	Pch Note 1	100	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Value at Tc = 25°C

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	-3.5	_		V	
	V _{IL}		_	-1.2	V	
Input current	I _{IH1}		_	-100	μΑ	$Vi = -8 V, V_{DS} = 0$
(Gate non shut down)	I _{IH2}	_	_	-50	μΑ	$Vi = -3.5 \text{ V}, V_{DS} = 0$
Input current	I _{IH(sd)1}	_	-0.3	_	mA	$Vi = -12 V, V_{DS} = 0$
(Gate shut down)	I _{IH(sd)2}	_	-0.11	_	mA	$Vi = -4.6 \text{ V}, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	Vop	-3.5	_	-12	V	
Drain current	I _{D limt}	-50	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
(Current limitation value)						

Notes: 4. Pulse test

Electrical Characteristics

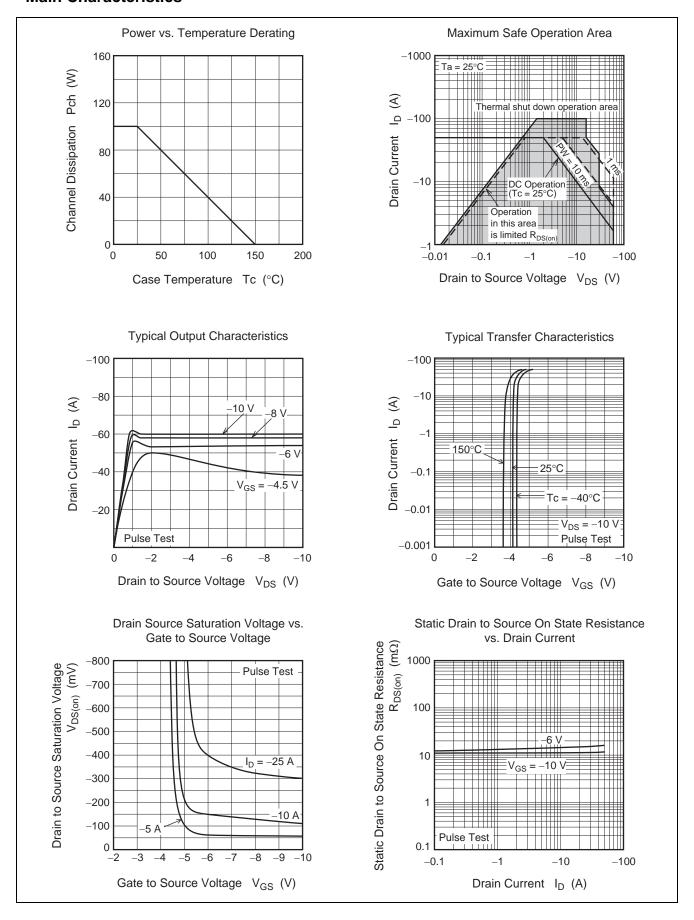
 $(Ta = 25^{\circ}C)$

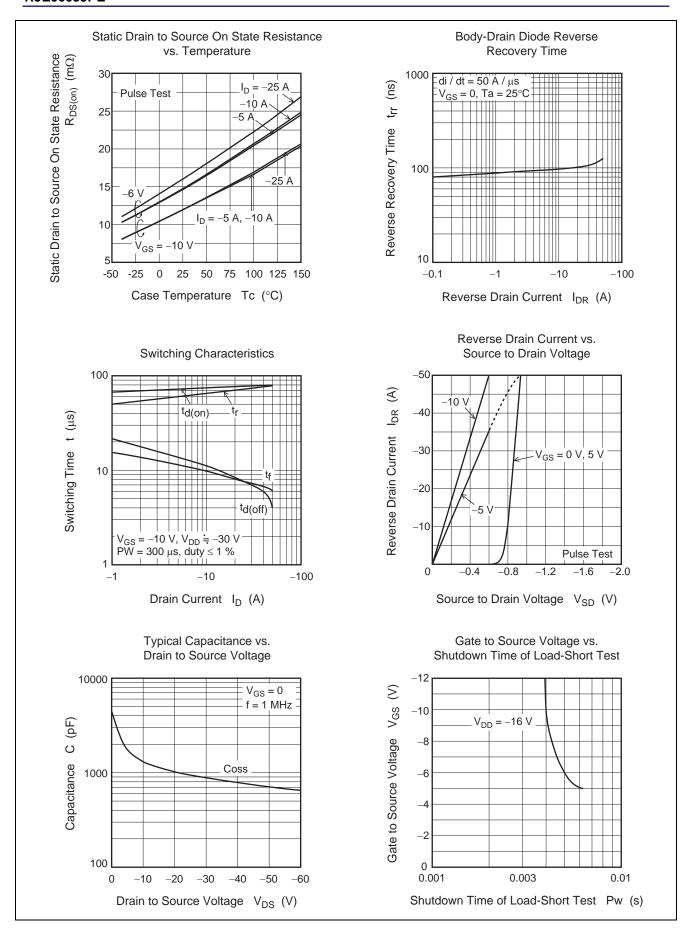
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}		_	-100	Α	$V_{GS} = -3.5 \text{ V}, V_{DS} = -10 \text{ V}$
	I _{D2}	_	_	-10	mA	$V_{GS} = -1.2 \text{ V}, V_{DS} = -10 \text{ V}$
	I _{D3}	-50	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
Drain to source breakdown voltage	V _{(BR)DSS}	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown	$V_{(BR)GSS}$	-16	_	_	V	$I_G = -800 \mu A, V_{DS} = 0$
voltage	V _{(BR)GSS}	2.5	_	_	V	$I_G = 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	-200	μΑ	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	I _{GSS}	_	_	-800	μΑ	$V_{GS} = -16 \text{ V}, V_{DS} = 0$
	I _{GSS}	_	_	100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS(OP)1}	_	-0.8	_	mA	$V_{GS} = -12 \text{ V}, V_{DS} = 0$
	I _{GS(OP)2}	_	-0.11	_	mA	$V_{GS} = -4.6 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-3.4	_	-4.6	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	16	30	mΩ	$I_D = -25 \text{ A}, V_{GS} = -6 \text{ V}^{\text{Note 5}}$
resistance	R _{DS(on)}	_	12	15	mΩ	$I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 5}}$
Output capacitance	Coss	_	1400	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{MHz}$
Turn-on delay time	t _{d(on)}	_	77.2	_	μS	$V_{GS} = -10 \text{ V}, I_{D} = -25 \text{ A},$
Rise time	t _r	_	72.7	_	μS	$R_L = 1.2 \Omega$
Turn-off delay time	t _{d(off)}	_	7.7	_	μS	
Fall time	t _f	_	7.7	_	μS	
Body-drain diode forward voltage	V_{DF}	_	-0.92	_	V	$I_F = -50 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	133	_	ns	$I_F = -50 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time Note 6	t _{os1}	_	6.3	_	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -16 \text{ V}$

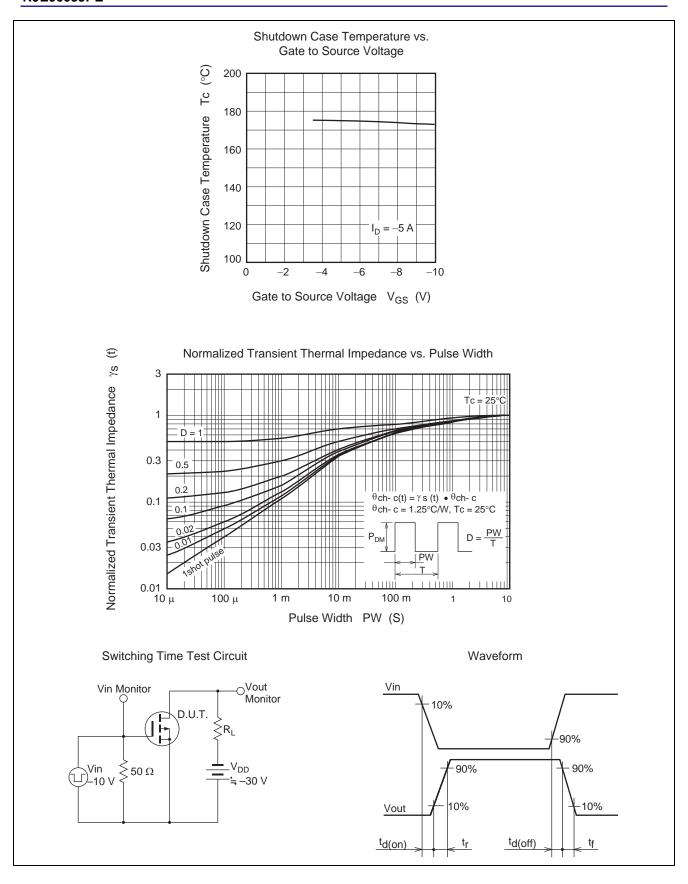
Notes: 5. Pulse test

6. Including the junction temperature rise of the over loaded condition.

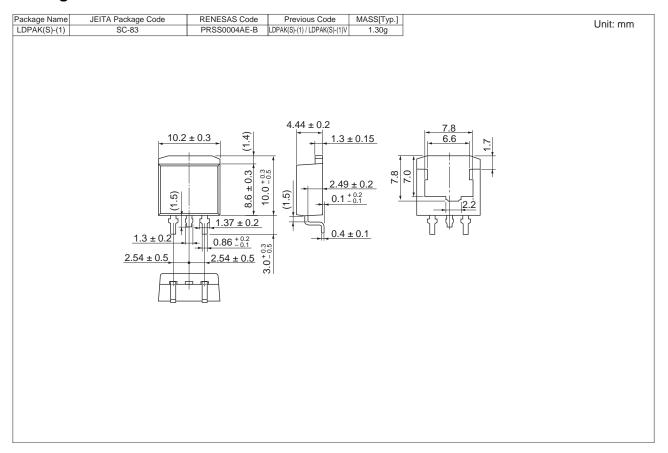
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJE0603JPE-00-J3	1000 pcs	Taping (Sinistrorse)

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